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| EFS ID:                              | 9373749  |  |
| Application Number:                  | 10563854   |  |
| International Application Number:    |  |  |
| Confirmation Number:                 | 3828   |  |
| Title of Invention:                  | Growth method for nitride semiconductor epitaxial layers |  |
| First Named Inventor/Applicant Name: | Euijoon Yoon   |  |
| Customer Number:                     | 27128  |  |
| Filer:                               | Samuel Digirolamo/Lisa Lilburn                           |  |
| Filer Authorized By:                 | Samuel Digirolamo  |  |
| Attorney Docket Number:              | 504478.24  |  |
| Receipt Date:                        | 03-FEB-2011  |  |
| Filing Date:                         | 09-JUN-2006  |  |
| Time Stamp:                          | 19:25:13   |  |
| Application Type:                    | U.S. National Stage under 35 USC 371                     |  |

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#### New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

#### National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

### New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.